



JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

TO-92 Plastic-Encapsulate Transistors

3DD13003B TRANSISTOR(NPN)

FEATURES

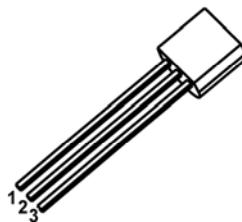
- power switching applications

TO-92

1. Emitter

2. Collector

3. Base



MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	700	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	9	V
I_c	Collector Current -Continuous	1.5	A
P_c	Collector Power Dissipation	0.9	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

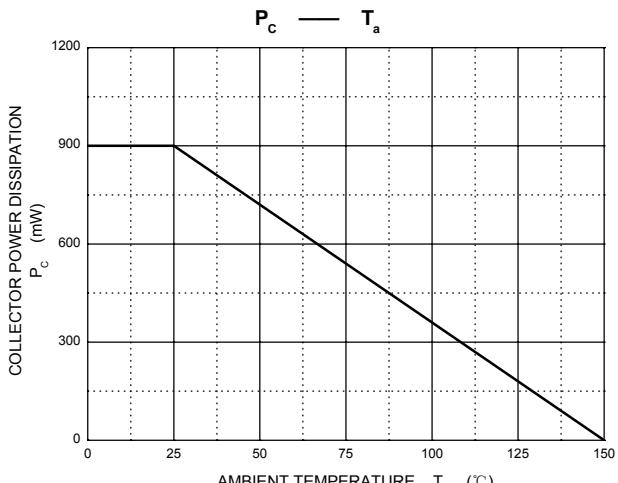
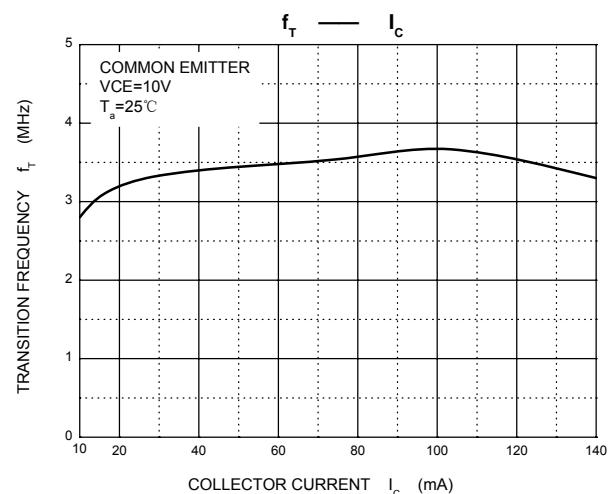
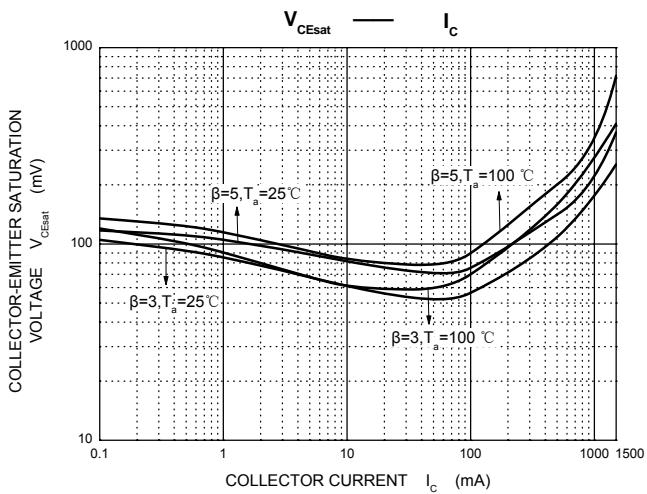
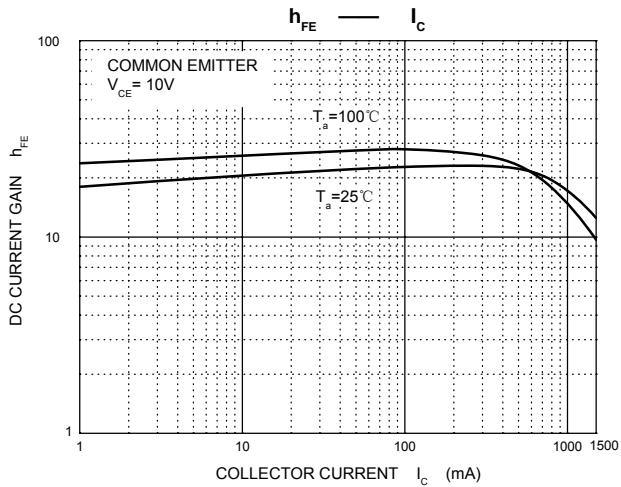
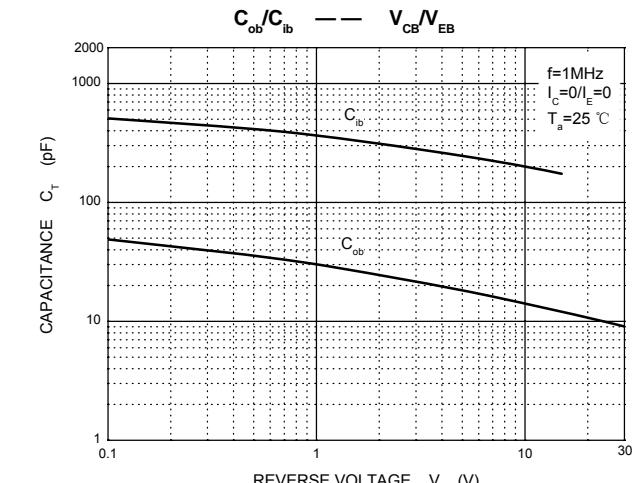
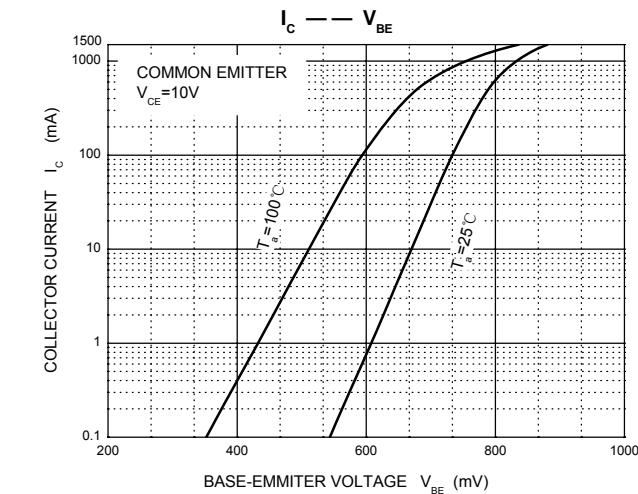
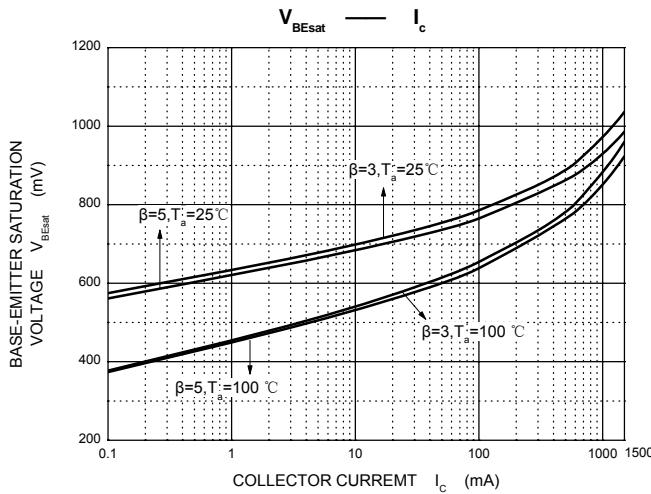
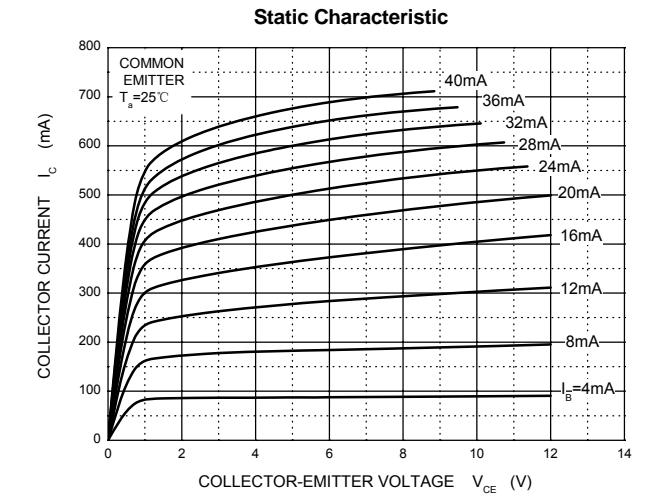
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=1\text{mA}, I_E=0$	700			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=10\text{mA}, I_B=0$	400			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=1\text{mA}, I_C=0$	9			V
Collector cut-off current	I_{CBO}	$V_{CB}=700\text{V}, I_E=0$			100	μA
Collector cut-off current	I_{CEO}	$V_{CE}=400\text{V}, I_B=0$			50	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=7\text{V}, I_C=0$			10	μA
DC current gain	h_{FE}	$V_{CE}=10\text{V}, I_C=0.4\text{ A}$	20		40	
Collector-emitter saturation voltage	$V_{CE(\text{sat})1}$	$I_C=1.5\text{A}, I_B=0.5\text{A}$			3	V
	$V_{CE(\text{sat})2}$	$I_C=0.5\text{A}, I_B=0.1\text{A}$			0.8	V
Base-emitter saturation voltage	$V_{BE(\text{sat})}$	$I_C=0.5\text{A}, I_B=0.1\text{A}$			1	V
Transition Frequency	f_T	$V_{CE}=10\text{V}, I_C=100\text{mA}, f=1\text{MHz}$	4			MHz
Fall time	t_f	$I_C=1\text{A}$			0.7	μs
Storage time	t_s	$I_{B1}=-I_{B2}=0.2\text{A}$			4	μs

CLASSIFICATION OF h_{FE}

Rank				
Range	20-25	25-30	30-35	35-40

Typical Characteristics

3DD13003B



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